

Complementary power Darlington transistors

Features

- Monolithic Darlington configuration
- Integrated antiparallel collector-emitter diode

Application

■ Linear and switching industrial equipment

Description

The devices are manufactured in planar technology with "base island" layout and monolithic Darlington configuration. The resulting transistors show exceptional high gain performance coupled with very low saturation voltage.

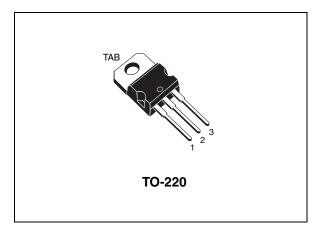


Figure 1. Internal schematic diagrams

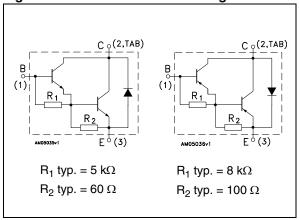


Table 1. Device summary

Part number	Marking	Polarity	Package	Packaging	
TIP142T	TIP142T	NPN	TO-220	Tube	
TIP147T	TIP147T	PNP	10-220	Tube	

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1 Absolute maximum ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-base voltage (I _E = 0)	100	V
V _{CEO}	Collector-emitter voltage (I _B = 0)	100	V
V _{EBO}	Emitter-base voltage (I _C = 0)	5	V
I _C	Collector current	10	Α
I _{CM}	Collector peak current	20	Α
I _B	Base current	0.5	Α
P _{TOT}	Total dissipation at T _{case} = 25 °C	90	W
T _{STG}	Storage temperature	-65 to 150	°C
TJ	Max. operating junction temperature	150	°C

Note: For PNP type voltage and current are negative.

Table 3. Thermal data

Symbol	Parameter		Unit
R _{thJC}	Thermal resistance junction-case max	1.4	°C/W

2 Electrical characteristics

 T_{case} = 25 °C; unless otherwise specified.

Table 4. Electrical characteristics

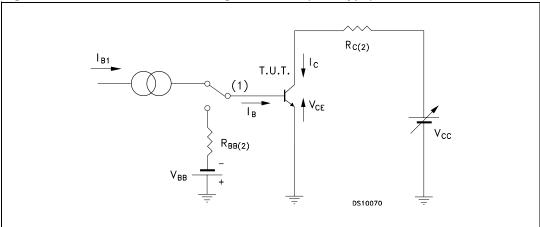
Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I _{CBO}	Collector cut-off current (I _E = 0)	V _{CB} = 100 V			1	mA
I _{CEO}	Collector cut-off current $(I_B = 0)$	V _{CE} = 50 V			2	mA
I _{EBO}	Emitter cut-off current (I _C = 0)	V _{EB} = 5 V			2	mA
V _{CEO(sus)} ⁽¹⁾	Collector-emitter sustaining voltage (I _B = 0)	I _C = 30 mA	100			V
V _{CE(sat)} ⁽¹⁾	Collector-emitter saturation voltage	$I_C = 5 \text{ A}$ $I_B = 10 \text{ mA}$ $I_C = 10 \text{ A}$ $I_B = 40 \text{ mA}$			2	V V
V _{BE(on)} ⁽¹⁾	Base-emitter on voltage	I _C = 10 A V _{CE} = 4 V			3	V
h _{FE} ⁽¹⁾	DC current gain	$I_C = 5 A$ $V_{CE} = 4 V$ $I_C = 10 A$ $V_{CE} = 4 V$	1000 500			
	Resistive load					
t _{on}	Turn-on time	$I_C = 10 \text{ A}$ $R_L = 3 \Omega$		0.9		μs
t _{off}	Turn-off time	$I_{B1} = -I_{B2} = 40 \text{ mA}$		4		μs

^{1.} Pulse test: pulse duration \leq 300 μ s, duty cycle \leq 2 %.

Note: For PNP type voltage and current are negative.

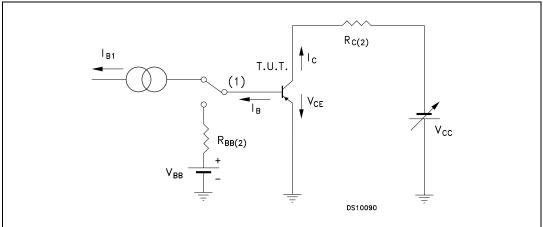
2.1 Test circuits

Figure 2. Resistive load switching test circuit (NPN type)



- 1. Fast electronic switch
- 2. Non-inductive resistor

Figure 3. Resistive load switching test circuit (PNP type)



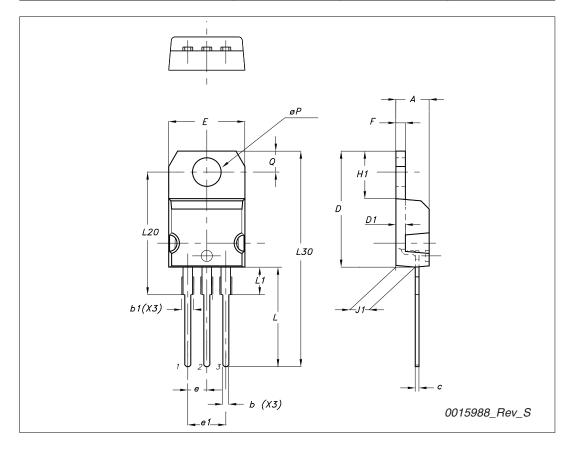
- 1. Fast electronic switch
- 2. Non-inductive resistor

3 Package mechanical data

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TO-220 type A mechanical data

Dim	mm		
DIM	Min	Тур	Max
A	4.40		4.60
b	0.61		0.88
b1	1.14		1.70
С	0.48		0.70
D	15.25		15.75
D1		1.27	
E	10		10.40
е	2.40		2.70
e1	4.95		5.15
F	1.23		1.32
H1	6.20		6.60
J1	2.40		2.72
L	13		14
L1	3.50		3.93
L20		16.40	
L30		28.90	
ØP	3.75		3.85
Q	2.65		2.95



TIP142T, TIP147T Revision history

4 Revision history

Table 5. Document revision history

Date	Revision	Changes
21-Jun-2004	4	
20-May-2010	5	Technology change from epitaxial base to planar base island.

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